

MC14532B

8-Bit Priority Encoder

The MC14532B is constructed with complementary MOS (CMOS) enhancement mode devices. The primary function of a priority encoder is to provide a binary address for the active input with the highest priority. Eight data inputs (D0 thru D7) and an enable input (E_{in}) are provided. Five outputs are available, three are address outputs (Q0 thru Q2), one group select (GS) and one enable output (E_{out}).

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-Power Schottky TTL Load over the Rated Temperature Range

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	- 0.5 to + 18.0	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	- 0.5 to $V_{DD} + 0.5$	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	- 65 to + 150	°C
T_L	Lead Temperature (8-Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.

†Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

Ceramic "L" Packages: - 12 mW/°C From 100°C To 125°C

TRUTH TABLE

Input										Output				
E_{in}	D7	D6	D5	D4	D3	D2	D1	D0	GS	Q2	Q1	Q0	E_{out}	
0	X	X	X	X	X	X	X	X	0	0	0	0	0	
1	0	0	0	0	0	0	0	0	0	0	0	0	1	
1	1	X	X	X	X	X	X	X	1	1	1	1	0	
1	0	1	X	X	X	X	X	X	1	1	1	0	0	
1	0	0	1	X	X	X	X	X	1	1	0	1	0	
1	0	0	0	1	X	X	X	X	1	1	0	0	0	
1	0	0	0	0	1	X	X	X	1	0	1	1	0	
1	0	0	0	0	0	1	X	X	1	0	1	0	0	
1	0	0	0	0	0	0	0	1	1	0	0	1	0	
1	0	0	0	0	0	0	0	0	0	0	0	0	0	

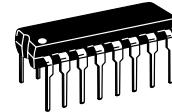
X = Don't Care

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



L SUFFIX
CERAMIC
CASE 620



P SUFFIX
PLASTIC
CASE 648



D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP	Plastic
MC14XXXBCL	Ceramic
MC14XXXBD	SOIC

$T_A = -55^\circ$ to 125° C for all packages.

PIN ASSIGNMENT

D4	1	●	16	V _{DD}
D5	2		15	E_{out}
D6	3		14	GS
D7	4		13	D ₃
E_{in}	5		12	D ₂
Q2	6		11	D ₁
Q1	7		10	D ₀
V _{SS}	8		9	Q ₀

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V _{DD} Vdc	−55°C		25°C			125°C		Unit
			Min	Max	Min	Typ #	Max	Min	Max	
Output Voltage "0" Level V _{in} = V _{DD} or 0	V _O L	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
	V _O H	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage "0" Level (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc)	V _I L	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc
		10	—	3.0	—	4.50	3.0	—	3.0	
		15	—	4.0	—	6.75	4.0	—	4.0	
	V _I H	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc
		10	7.0	—	7.0	5.50	—	7.0	—	
		15	11	—	11	8.25	—	11	—	
Output Drive Current (V _O H = 2.5 Vdc) (V _O H = 4.6 Vdc) (V _O H = 9.5 Vdc) (V _O H = 13.5 Vdc)	Source	I _O H	5.0	−3.0	—	−2.4	−4.2	—	−1.7	mAdc
			5.0	−0.64	—	−0.51	−0.88	—	−0.36	
			10	−1.6	—	−1.3	−2.25	—	−0.9	
			15	−4.2	—	−3.4	−8.8	—	−2.4	
	Sink	I _O L	5.0	0.64	—	0.51	0.88	—	0.36	mAdc
			10	1.6	—	1.3	2.25	—	0.9	
			15	4.2	—	3.4	8.8	—	2.4	
Input Current	I _{in}	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	μAdc
Input Capacitance (V _{in} = 0)	C _{in}	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	I _{DD}	5.0	—	5.0	—	0.005	5.0	—	150	μAdc
Total Supply Current***† (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching)	I _T	10	—	10	—	0.010	10	—	300	μAdc
		15	—	20	—	0.015	20	—	600	
		5.0	—	—	—	I _T = (1.74 μA/kHz) f + I _{DD}	—	—	—	
		10	—	—	—	I _T = (3.65 μA/kHz) f + I _{DD}	—	—	—	
		15	—	—	—	I _T = (5.73 μA/kHz) f + I _{DD}	—	—	—	

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

**The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

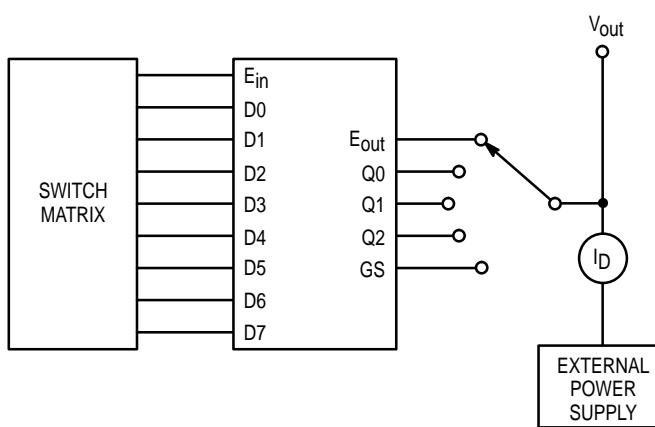
where: I_T is in μA (per package), C_L in pF, V = (V_{DD} − V_{SS}) in volts, f in kHz is input frequency, and k = 0.005.

SWITCHING CHARACTERISTICS* ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

Characteristic	Symbol	V_{DD}	Min	Typ #	Max	Unit
Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t_{TLH}, t_{THL}	5.0 10 15	— — —	100 50 40	200 100 80	ns
Propagation Delay Time — E_{in} to E_{out} $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 120 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 77 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 55 \text{ ns}$	t_{PLH}, t_{PHL}	5.0 10 15	— — —	205 110 80	410 220 160	ns
Propagation Delay Time — E_{in} to GS $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 90 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 57 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 40 \text{ ns}$	t_{PLH}, t_{PHL}	5.0 10 15	— — —	175 90 65	350 180 130	ns
Propagation Delay Time — E_{in} to Q_n $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 195 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 107 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$	t_{PHL}, t_{PLH}	5.0 10 15	— — —	280 140 100	560 280 200	ns
Propagation Delay Time — D_n to Q_n $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 265 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 137 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 85 \text{ ns}$	t_{PLH}, t_{PHL}	5.0 10 15	— — —	300 170 110	600 340 220	ns
Propagation Delay Time — D_n to GS $t_{PLH}, t_{PHL} = (1.7 \text{ ns/pF}) C_L + 195 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.66 \text{ ns/pF}) C_L + 107 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$	t_{PLH}, t_{PHL}	5.0 10 15	— — —	280 140 100	560 280 200	ns

* The formulas given are for the typical characteristics only at 25°C .

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



Output Under Test	$V_{GS} = V_{DD}$		$V_{GS} = -V_{DD}$		
	$V_{DS} = V_{out}$	Sink Current	$V_{DS} = V_{out} - V_{DD}$	Source Current	
E_{out}	X	0	0	0	1
Q_0	X	0	0	1	1
Q_1	X	0	0	1	1
Q_2	X	0	0	1	1
GS	X	0	0	1	1

Figure 1. Typical Sink and Source Current Characteristics

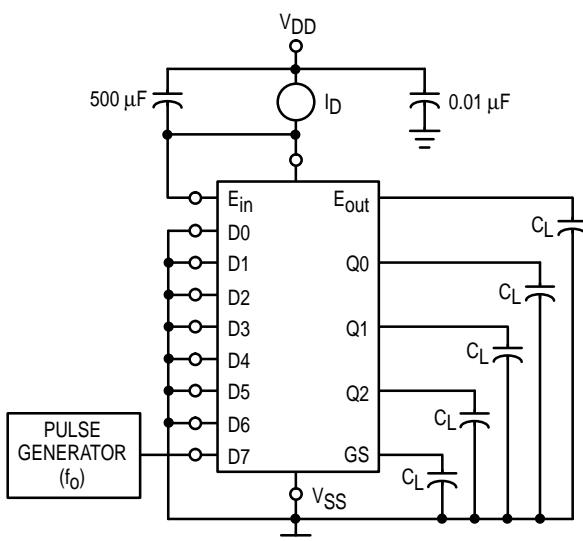
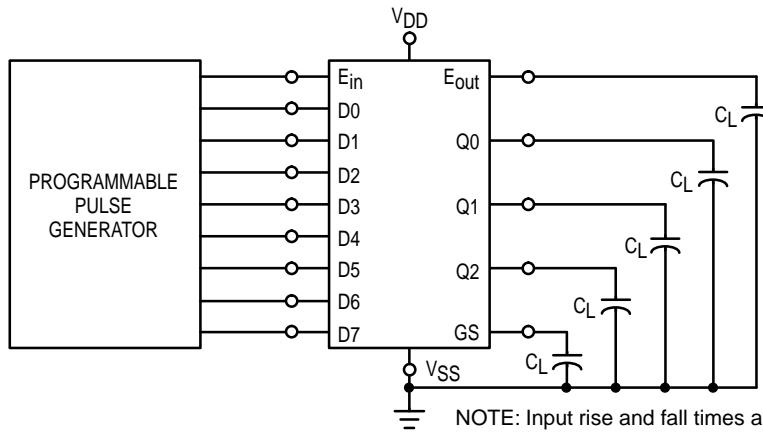


Figure 2. Typical Power Dissipation Test Circuit



NOTE: Input rise and fall times are 20 ns

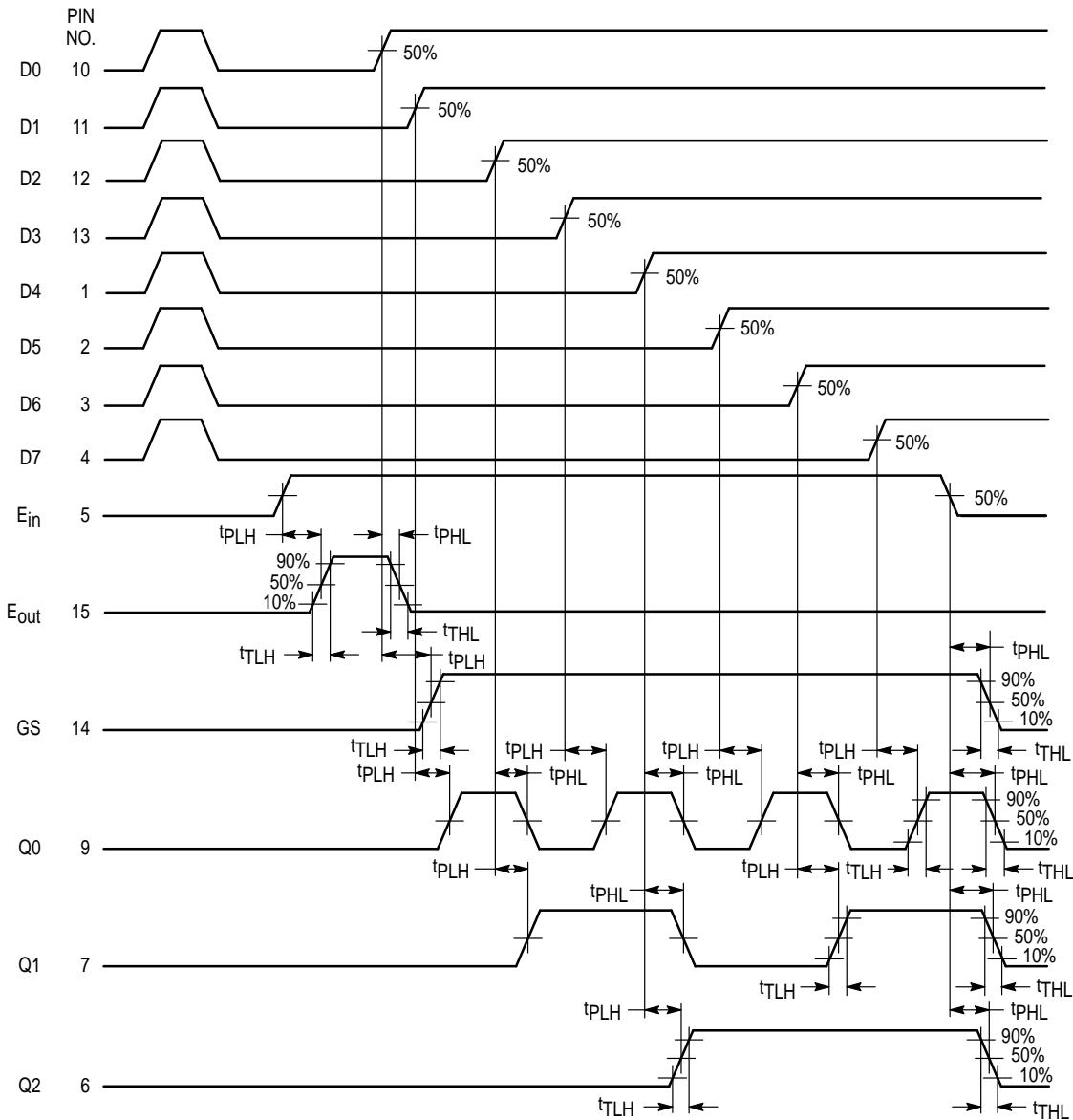


Figure 3. AC Test Circuit and Waveforms

**LOGIC DIAGRAM
(Positive Logic)**

LOGIC EQUATIONS

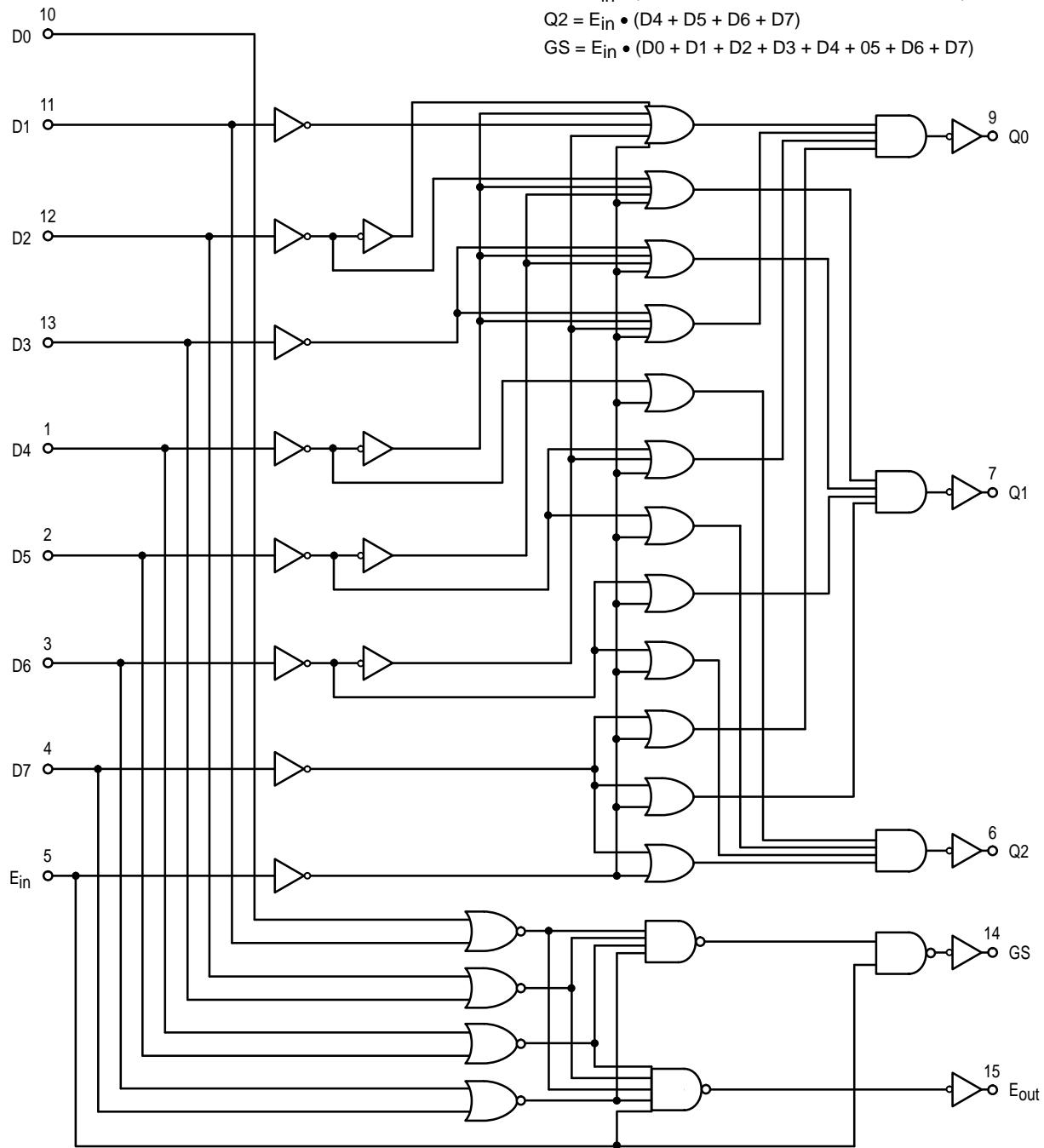
$$E_{out} = E_{in} \cdot \bar{D}_0 \cdot \bar{D}_1 \cdot \bar{D}_2 \cdot \bar{D}_3 \cdot \bar{D}_4 \cdot \bar{D}_5 \cdot \bar{D}_6 \cdot \bar{D}_7$$

$$Q_0 = E_{in} \cdot (D_1 \cdot \bar{D}_2 \cdot \bar{D}_4 \cdot \bar{D}_6 + D_3 \cdot \bar{D}_4 \cdot \bar{D}_6 + D_5 \cdot \bar{D}_6 + D_7)$$

$$Q_1 = E_{in} \cdot (D_2 \cdot \bar{D}_4 \cdot \bar{D}_5 + D_3 \cdot \bar{D}_4 \cdot \bar{D}_5 + D_6 + D_7)$$

$$Q_2 = E_{in} \cdot (D_4 + D_5 + D_6 + D_7)$$

$$GS = E_{in} \cdot (D_0 + D_1 + D_2 + D_3 + D_4 + D_5 + D_6 + D_7)$$



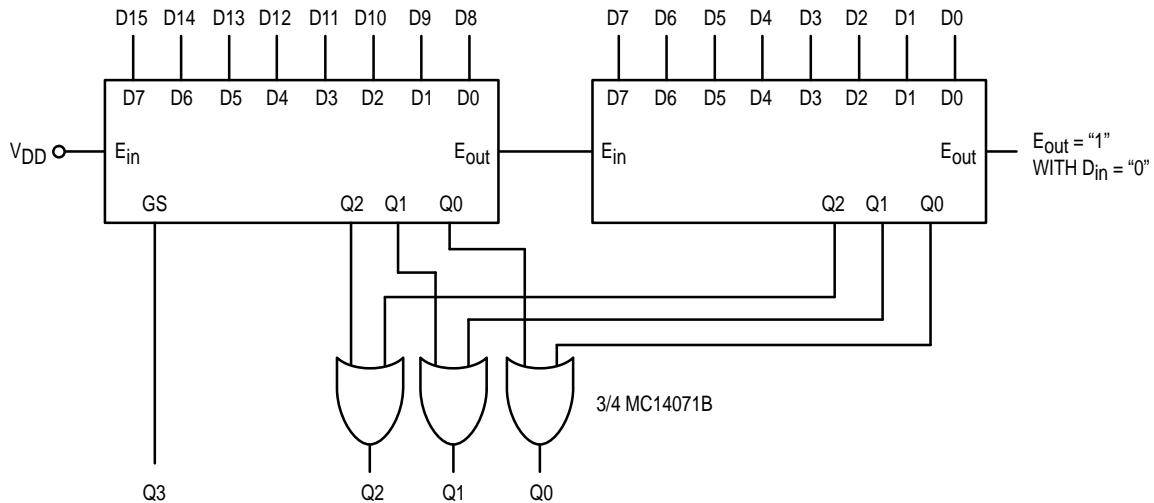


Figure 4. Two MC14532B's Cascaded for 4-Bit Output

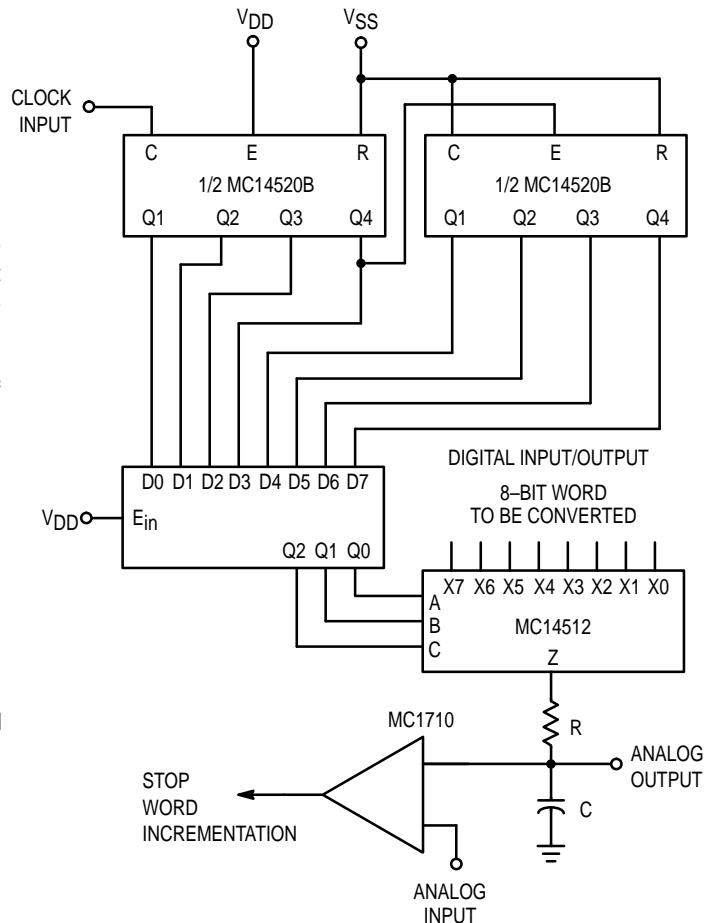
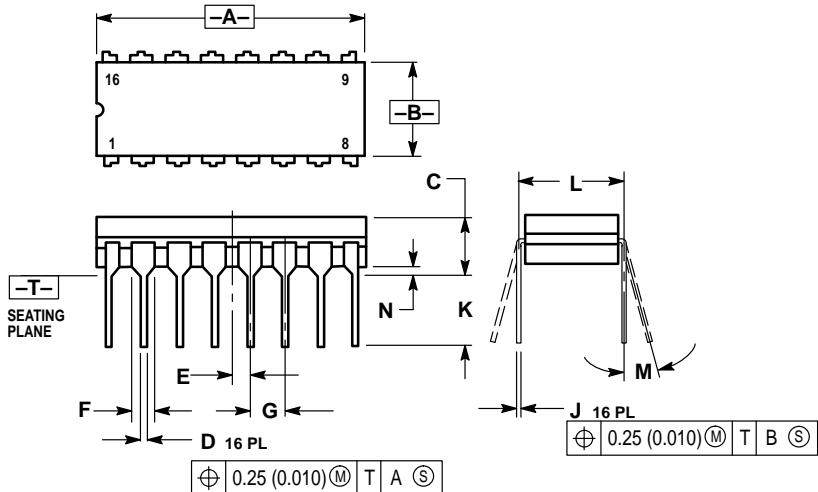


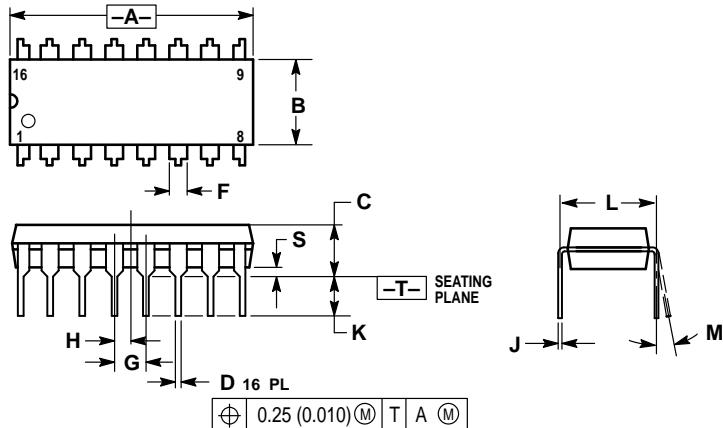
Figure 5. Digital to Analog and Analog to Digital Converter

OUTLINE DIMENSIONS

L SUFFIX
CERAMIC DIP PACKAGE
CASE 620-10
ISSUE V

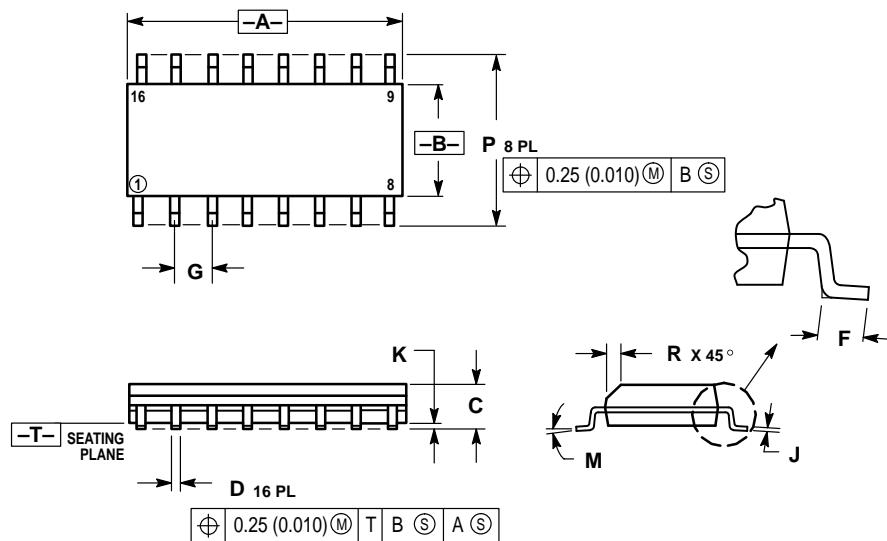


P SUFFIX
PLASTIC DIP PACKAGE
CASE 648-08
ISSUE R



OUTLINE DIMENSIONS

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B-05
ISSUE J



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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MC14532B/D

